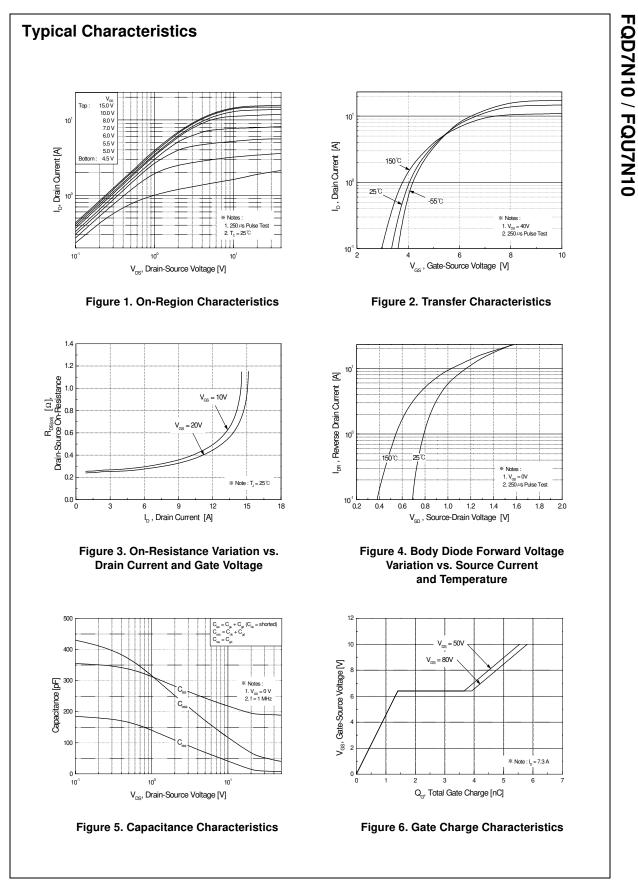


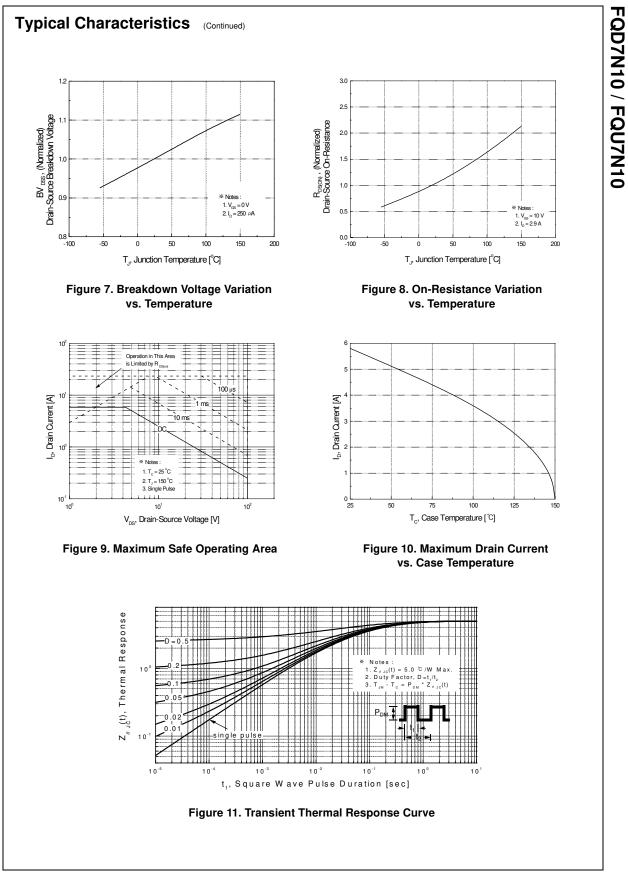
# **Thermal Characteristics**

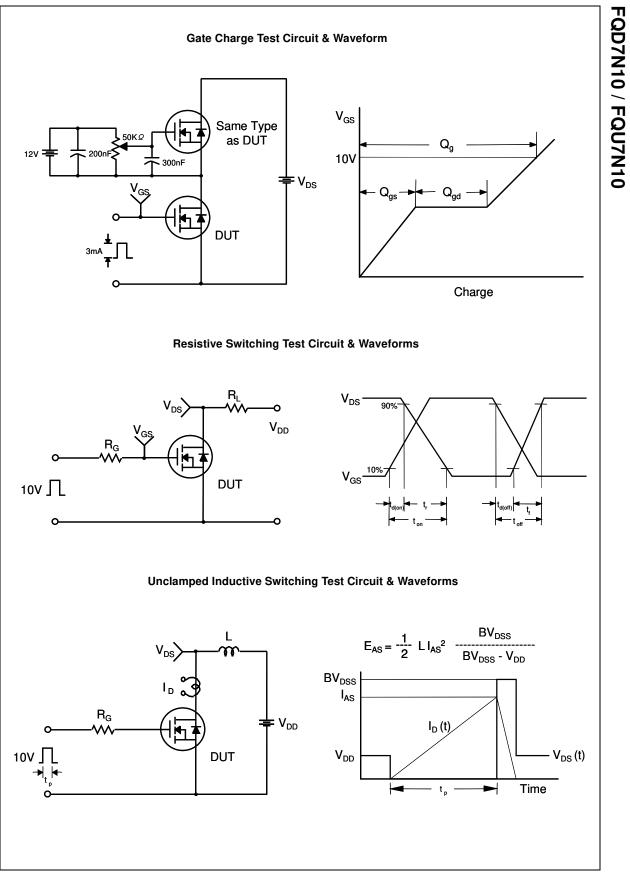
Symbol	Parameter	Тур	Max	Units
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case		5.0	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction-to-Ambient *		50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		110	°C/W

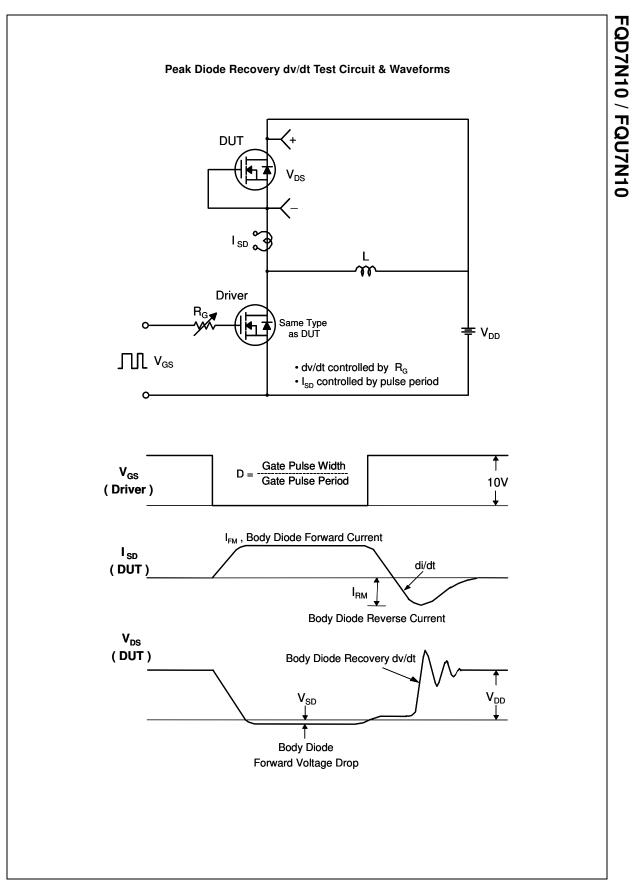
©2008 Fairchild Semiconductor International

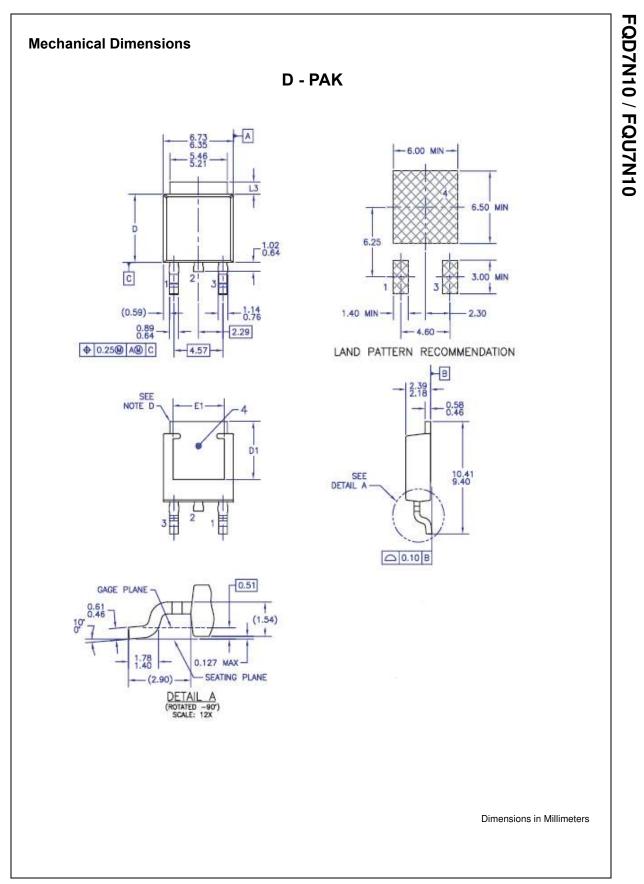
Symbol	Parameter	Test Conditions	6	Min	Тур	Max	Units
Off Cha	racteristics						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = 250 \mu A$		100			V
ΔBV <sub>DSS</sub> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C			0.1		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V				1	μA
		V <sub>DS</sub> = 80 V, T <sub>C</sub> = 125°C				10	μA
GSSF	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 25 V, V <sub>DS</sub> = 0 V				100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = -25 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
	venteviation					1	
Jn Cna / <sub>GS(th)</sub>	racteristics Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA		2.0		4.0	V
R <sub>DS(on)</sub>	Static Drain-Source	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.9 \text{ A}$			0.28	0.35	Ω
	On-Resistance						
ĴFS	Forward Transconductance	$V_{DS} = 40$ V, $I_{D} = 2.9$ A	(Note 4)		3.3		S
Dvnami	c Characteristics						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V,			190	250	pF
Coss	Output Capacitance	f = 1.0 MHz			60	75	pF
D <sub>rss</sub>	Reverse Transfer Capacitance				10	13	pF
	ng Characteristics				7	05	
d(on)	Turn-On Delay Time	V <sub>DD</sub> = 50 V, I <sub>D</sub> = 7.3 A,			7	25	ns
r	Turn-On Rise Time	R <sub>G</sub> = 25 Ω	$R_{G} = 25 \Omega$		24	60	ns
d(off)	Turn-Off Delay Time	(Note 4, 5)			13	35	ns
f	Turn-Off Fall Time		( , .,		19	50	ns
ל <sup>g</sup>	Total Gate Charge	$V_{DS} = 80 \text{ V}, I_D = 7.3 \text{ A},$ $V_{GS} = 10 \text{ V}$ (Note 4. 5)			5.8	7.5	nC
2 <sub>gs</sub>	Gate-Source Charge				1.4		nC
2 <sub>gd</sub>	Gate-Drain Charge		(11018 4, 5)		2.5		nC
Drain-S	ource Diode Characteristics ar	nd Maximum Rating	s				
S	Maximum Continuous Drain-Source Diode Forward Current				5.8	Α	
SM	Maximum Pulsed Drain-Source Diode F	Forward Current				23.2	Α
/ <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 5.8 A				1.5	V
rr	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 7.3 A,		70		ns	
ג גיי	Reverse Recovery Charge	dI <sub>F</sub> / dt = 100 A/µs			150		nC
otes: Repetitive R L = 2.23mH, I <sub>SD</sub> ≤ 7.3A, c	ating : Pulse width limited by maximum junction temper $I_{AS} = 5.8A$ , $V_{DD} = 25V$ , $R_G = 25 \Omega$ , Starting $T_J = 25^{\circ}C$ $I/dt \le 300A/\mu s$ , $V_{DD} \le BV_{DSS}$ , Starting $T_J = 25^{\circ}C$ Pulse width $\le 300\mu s$ , Duty cycles $2\%$						

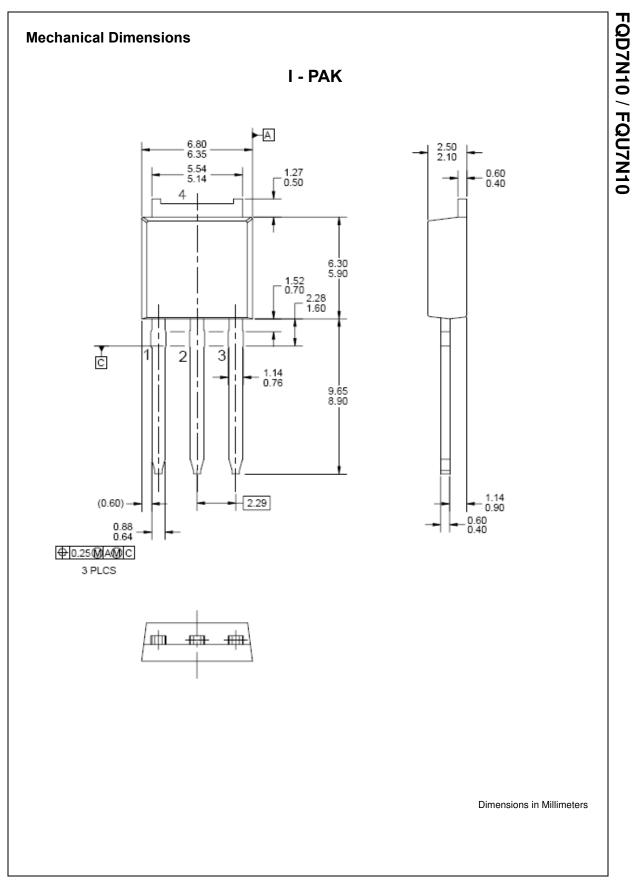














## SEMICONDUCTOR

#### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

Build it Now™ CorePLUS™ CorePOWER™ CROSSVOLT™ CTI ™ Current Transfer Logic™ EcoSPARK<sup>®</sup> EfficentMax™ EZSWITCH™ \*

Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT® FAST® FastvCore™ FlashWriter<sup>®</sup> \* **FPS™** F-PFS™

IntelliMAX™ ISOPI ANAR<sup>TM</sup> MegaBuck<sup>™</sup> MICROCOUPLER™ MicroFET™ MicroPak™ MillerDrive™ MotionMax™ Motion-SPM™ OPTOLOGIC<sup>®</sup> OPTOPLANAR<sup>®</sup> PDP SPM™ Power-SPM™ PowerTrench<sup>®</sup>

PowerXS™

FRFET®

GTO™

Green FPS™

Global Power Resource<sup>SM</sup>

Green FPS™ e-Series™

Programmable Active Droop™ QFET QS™ Quiet Series™ RapidConfigure™ Saving our world, 1mW /W /kW at a time™ SmartMax™ SMART START™ SPM<sup>®</sup>

STEALTH™ SuperFET™ SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS™ SyncFET™ The Power Franchise<sup>®</sup> TinyBuck™ TinyLogic<sup>®</sup> TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ μSerDes™ u SerDes UHC<sup>®</sup>

Uwer p we franchise

TinyBoost™

Ultra FRFET™ UniFET™

VCX™ VisualMax™ XS™

\* EZSWITCH™ and FlashWriter<sup>®</sup> are trademarks of System General Corporation, used under license by Fairchild Semiconductor

### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

#### As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Farichild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Farichild strongly encourages customers to purchase Farichild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Farichild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Farichild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
		Rev.